SCLS131B - DECEMBER 1982 - REVISED MAY 1997

- High-Current 3-State Outputs Drive Bus Lines Directly or up to 15 LSTTL Loads
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

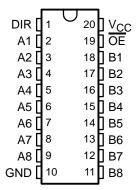
#### description

These octal bus transceivers are designed for asynchronous two-way communication between data buses. The control-function implementation minimizes external timing requirements.

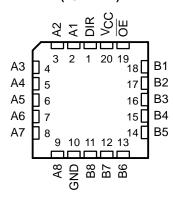
The devices allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable  $(\overline{OE})$  input can be used to disable the device so that the buses are effectively isolated.

The SN54HC245 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74HC245 is characterized for operation from -40°C to 85°C.

SN54HC245 . . . J OR W PACKAGE SN74HC245 . . . DB, DW, N, OR PW PACKAGE (TOP VIEW)



## SN54HC245 . . . FK PACKAGE (TOP VIEW)



#### **FUNCTION TABLE**

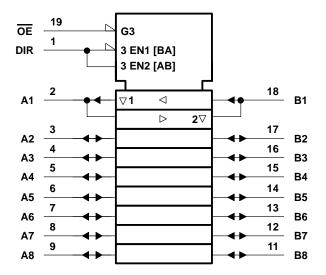
INP	UTS	ODEDATION
OE	DIR	OPERATION
L	L	B data to A bus
L	Н	A data to B bus
Н	X	Isolation



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

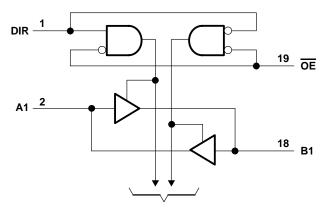


### logic symbol†



<sup>&</sup>lt;sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

### logic diagram (positive logic)



To Seven Other Channels

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#### absolute maximum ratings over operating free-air temperature range†

O and alternative M		0.51/1: 71/
Supply voltage range, V <sub>CC</sub>		
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0 or V <sub>I</sub> > V <sub>CC</sub> )	) (see Note 1)	±20 mA
Output clamp current, IOK (VO < 0 or VO >	V <sub>CC</sub> ) (see Note 1)	±20 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_O$	CC)	±35 mA
Continuous current through V <sub>CC</sub> or GND	 	±70 mA
Package thermal impedance, θ <sub>JA</sub> (see Note	e 2): DB package	115°C/W
	DW package	97°C/W
	N package	67°C/W
	PW package	128°C/W
Storage temperature range, T <sub>sto</sub>		

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

#### recommended operating conditions

			AS	SN54HC245		SN74HC245			UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	UNII
Vcc	Supply voltage		2	5	6	2	5	6	V
		V <sub>CC</sub> = 2 V	1.5			1.5			
ViH	High-level input voltage	V <sub>CC</sub> = 4.5 V	3.15			3.15			V
		VCC = 6 V	4.2			4.2			
	Low-level input voltage	V <sub>CC</sub> = 2 V	0		0.5	0		0.5	
VIL		V <sub>CC</sub> = 4.5 V	0		1.35	0		1.35	V
		VCC = 6 V	0		1.8	0		1.8	
٧ <sub>I</sub>	Input voltage		0		VCC	0		VCC	V
٧o	Output voltage		0		VCC	0		VCC	V
		V <sub>CC</sub> = 2 V	0		1000	0		1000	
t <sub>t</sub>	Input transition (rise and fall) time	V <sub>CC</sub> = 4.5 V	0		500	0		500	ns
		V <sub>CC</sub> = 6 V	0		400	0		400	
TA	Operating free-air temperature		-55		125	-40		85	°C



## SN54HC245, SN74HC245 OCTAL BUS TRANSCEIVERS **WITH 3-STATE OUTPUTS**

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#### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DAD	AMETER	TEST CONDITIONS		Vaa	Т	A = 25°C	;	SN54HC245		SN74HC245		UNIT
PARAMETER		TEST CONDITIONS		vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
				2 V	1.9	1.998		1.9		1.9		
			I <sub>OH</sub> = -20 μA	4.5 V	4.4	4.499		4.4		4.4		
۷он		VI = VIH or VIL		6 V	5.9	5.999		5.9		5.9		V
			$I_{OH} = -6 \text{ mA}$	4.5 V	3.98	4.3		3.7		3.84		
			$I_{OH} = -7.8 \text{ mA}$	6 V	5.48	5.8		5.2		5.34		
				2 V		0.002	0.1		0.1		0.1	
	V <sub>I</sub> = V <sub>IH</sub> or		I <sub>OL</sub> = 20 μA	4.5 V		0.001	0.1		0.1		0.1	
VOL		VI = VIH or VIL		6 V		0.001	0.1		0.1		0.1	V
			$I_{OL} = 6 \text{ mA}$	4.5 V		0.17	0.26		0.4		0.33	
			$I_{OL} = 7.8 \text{ mA}$	6 V		0.15	0.26		0.4		0.33	
Ц	DIR or OE	$V_I = V_{CC}$ or 0		6 V		±0.1	±100		±1000		±1000	nA
loz	A or B	$V_O = V_{CC}$ or 0		6 V		±0.01	±0.5		±10		±5	μΑ
ICC		$V_I = V_{CC}$ or 0,	I <sub>O</sub> = 0	6 V			8		160		80	μΑ
Ci	DIR or OE			2 V to 6 V		3	10		10		10	pF

# switching characteristics over recommended operating free-air temperature range, $C_L$ = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	Vaa	T,	λ = 25°C	;	SN54H	C245	SN74H	IC245	UNIT
FARAMETER	(INPUT)	(OUTPUT)	VCC	MIN	MIN TYP M	MAX	MIN	MAX	MIN	MAX	UNIT
			2 V		40	105		160		130	
<sup>t</sup> pd	A or B	B or A	4.5 V		15	21		32		26	ns
			6 V		12	18		27		22	
	ŌĒ	A or B	2 V		125	230		340		290	
t <sub>en</sub>			4.5 V		23	46		68		58	ns
				6 V		20	39		58		49
	ŌĒ	<del>OE</del> A or B	2 V		74	200		300		250	
<sup>t</sup> dis			4.5 V		25	40		60		50	ns
			6 V		21	34		51		43	
		A or B	2 V		20	60		90		75	
t <sub>t</sub>			4.5 V		8	12		18		15	ns
			6 V		6	10		15		13	



## SN54HC245, SN74HC245 **OCTAL BUS TRÁNSCEIVERS** WITH 3-STATE OUTPUTS SCLS131B – DECEMBER 1982 – REVISED MAY 1997

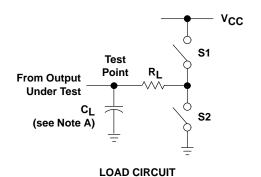
# switching characteristics over recommended operating free-air temperature range, $C_L$ = 150 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	FROM TO		T,	4 = 25°C	;	SN54H	IC245	SN74H	IC245	UNIT																				
	(INPUT)	(OUTPUT)	Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	ONII																				
			2 V		54	135		200		170																					
<sup>t</sup> pd	A or B	B or A	4.5 V		18	27		40		34	ns																				
																							ľ	6 V		15	23		34		29
			2 V		150	270		405		335																					
t <sub>en</sub>	ŌĒ	A or B	A or B	4.5 V		31	54		81		67	ns																			
			6 V		25	46		69		56																					
				2 V		45	210		315		265																				
t <sub>t</sub>		A or B	4.5 V		17	42		63		53	ns																				
			6 V		13	36		53		45																					

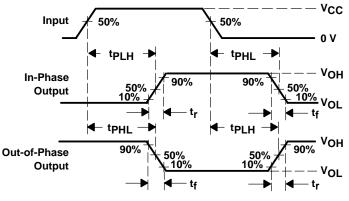
## operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance per transceiver	No load	40	pF

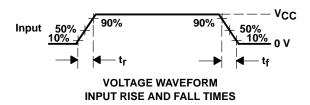
#### PARAMETER MEASUREMENT INFORMATION

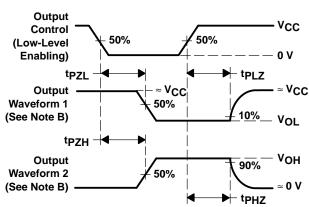


PARAI	METER	RL	CL	S1	S2	
	tPZH	<b>1 k</b> Ω	50 pF or	Open	Closed	
ten	tPZL	1 K22	150 pF	Closed	Open	
	tPHZ	<b>1 k</b> Ω	50 pF	Open	Closed	
tdis	tPLZ	1 K22	30 pr	Closed	Open	
t <sub>pd</sub> or t <sub>t</sub>			50 pF or 150 pF	Open	Open	



VOLTAGE WAVEFORMS
PROPAGATION DELAY AND OUTPUT TRANSITION TIMES





VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES FOR 3-STATE OUTPUTS

- NOTES: A. C<sub>L</sub> includes probe and test-fixture capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O = 50 \Omega$ ,  $t_r = 6 \text{ ns.}$
  - D. The outputs are measured one at a time with one input transition per measurement.
  - E. tpLz and tpHz are the same as tdis.
  - F. tpzL and tpzH are the same as ten.
  - G. tpLH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms



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